



BAT54XV2

SILICON EPITAXIAL PLANAR SCHOTTKY BARRIER DIODE

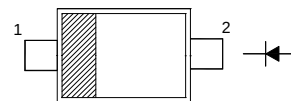
Reverse Voltage - 20V Forward Current - 1.0A

for low current rectification and high speed switching applications

Features

- Extremely small surface mounting type

Marking code: JV



Top View

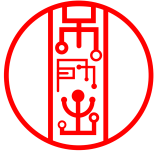
PIN	DESCRIPTION
1	Cathode
2	Anode

Absolute Maximum Ratings ($T_a = 25\text{ }^{\circ}\text{C}$)

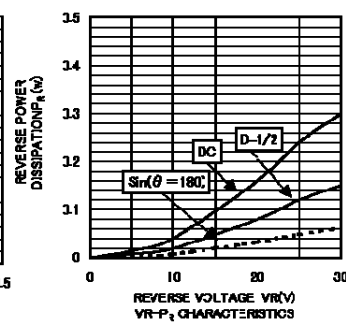
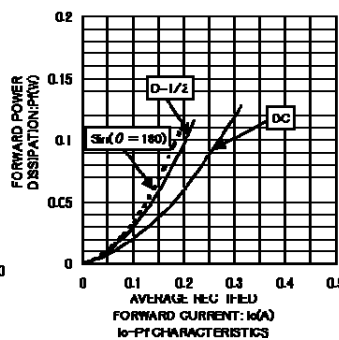
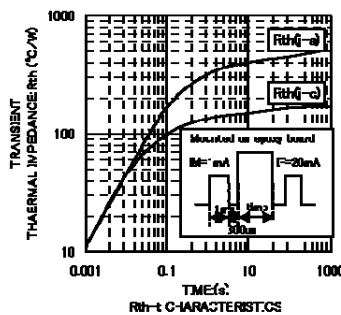
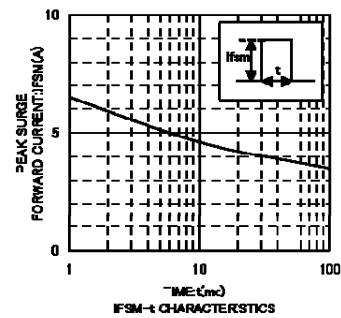
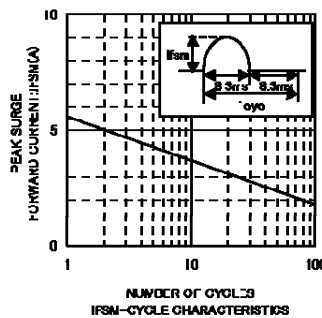
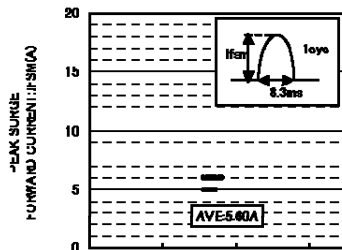
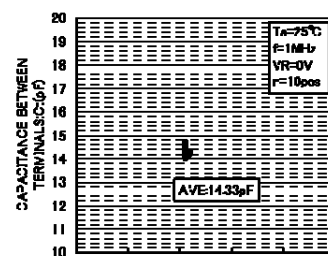
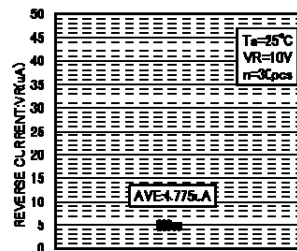
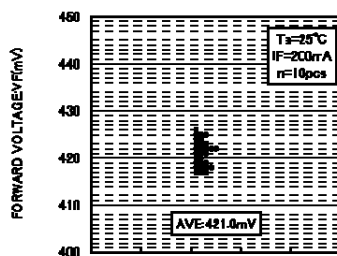
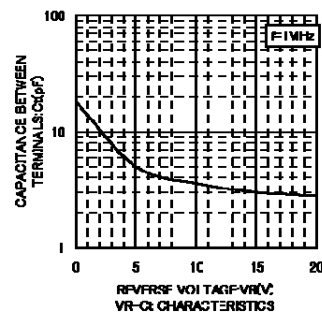
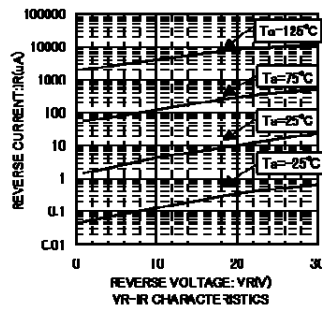
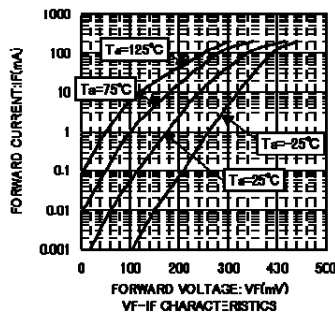
Parameter	Symbol	Value	Unit
Reverse Voltage	V_R	30	V
Mean Rectifying Current	I_O	200	mA
Peak Forward Surge Current (60Hz for Cyc.)	I_{FSM}	1	A
Junction Temperature	T_j	125	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	- 40 to + 125	$^{\circ}\text{C}$

Characteristics at $T_a = 25\text{ }^{\circ}\text{C}$

Parameter	Symbol	Max.	Unit
Forward Voltage at $I_F = 200\text{ mA}$	V_F	0.6	V
Reverse Current at $V_R = 10\text{ V}$	I_R	30	μA



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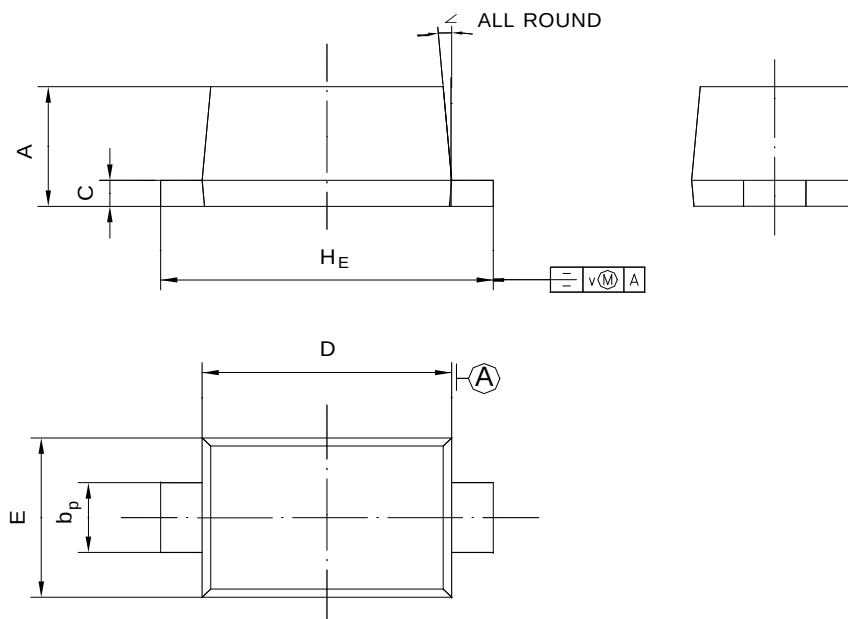


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PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-523



UNIT	A	b _p	C	D	E	H _E	V	∠
mm	0.70 0.60	0.4 0.3	0.135 0.100	1.25 1.15	0.85 0.75	1.7 1.5	0.1	5°